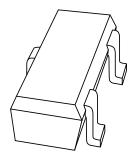
### DISCRETE SEMICONDUCTORS

# DATA SHEET



# **1PS184** High-speed double diode

Product specification Supersedes data of December 1993 File under Discrete Semiconductors, SC01 1996 Apr 03





# **High-speed double diode**

1PS184

#### **FEATURES**

- Small plastic SMD package
- High switching speed: max. 4 ns
- Continuous reverse voltage: max. 80 V
- Repetitive peak reverse voltage: max. 85 V
- Repetitive peak forward current: max. 500 mA
- Forward voltage: max. 1.2 V.

#### **APPLICATIONS**

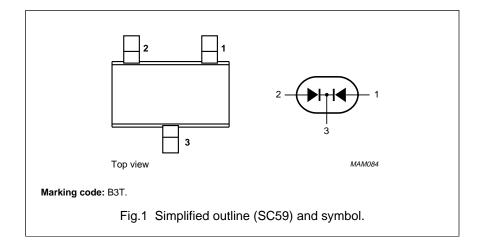
 High-speed switching in e.g. surface mounted circuits.

#### **DESCRIPTION**

The 1PS184 consists of two high-speed switching diodes with common cathodes, fabricated in planar technology, and encapsulated in the small plastic SMD SC59 package.

#### **PINNING**

PIN	PIN DESCRIPTION	
1	anode (a1)	
2	anode (a2)	
3	common cathode	



#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode					
V <sub>RRM</sub>	repetitive peak reverse voltage		_	85	V
$V_R$	continuous reverse voltage		_	80	V
I <sub>F</sub>	continuous forward current	single diode loaded; see Fig.2; note 1	_	215	mA
		double diode loaded; see Fig.2; note 1	_	125	mA
I <sub>FRM</sub>	repetitive peak forward current		_	500	mA
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; $T_j = 25$ °C prior to surge			
		t = 1 μs	_	4	A
		t = 1 s	_	0.5	A
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; note 1	_	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>j</sub>	junction temperature		_	150	°C

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#### Note

1. Device mounted on an FR4 printed-circuit board.

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# High-speed double diode

1PS184

#### **ELECTRICAL CHARACTERISTICS**

 $T_i = 25$  °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
Per diode					
V <sub>F</sub>	forward voltage	see Fig.3			
		I <sub>F</sub> = 1 mA	610	_	mV
		I <sub>F</sub> = 10 mA	740	_	mV
		I <sub>F</sub> = 50 mA	_	1.0	V
		I <sub>F</sub> = 100 mA	_	1.2	V
I <sub>R</sub>	reverse current	see Fig.4			
		V <sub>R</sub> = 25 V	_	30	nA
		V <sub>R</sub> = 80 V	_	0.5	μΑ
		V <sub>R</sub> = 25 V; T <sub>j</sub> = 150 °C	_	30	μΑ
		V <sub>R</sub> = 80 V; T <sub>j</sub> = 150 °C	_	100	μΑ
$C_d$	diode capacitance	$f = 1 \text{ MHz}$ ; $V_R = 0$ ; see Fig.5	-	1.5	pF
t <sub>rr</sub>	reverse recovery time	when switched from $I_F$ = 10 mA to $I_R$ = 10 mA; $R_L$ = 100 $\Omega$ ; measured at $I_R$ = 1 mA; see Fig.6	-	4	ns
V <sub>fr</sub>	forward recovery voltage	when switched from $I_F = 10$ mA; $t_r = 20$ ns; see Fig.7	ı	1.75	V

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-tp</sub>	thermal resistance from junction to tie-point		250	K/W
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	500	K/W

#### Note

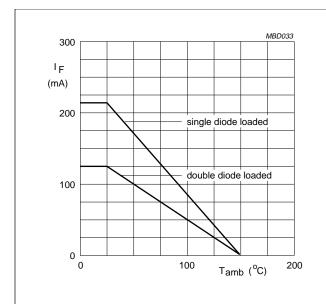
1. Device mounted on an FR4 printed-circuit board.

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# High-speed double diode

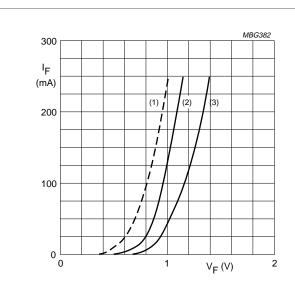
1PS184

#### **GRAPHICAL DATA**



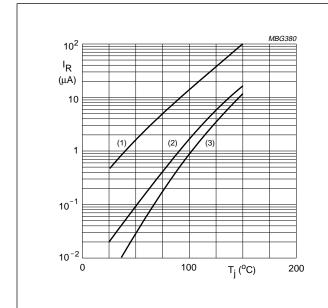
Device mounted on an FR4 printed-circuit board.

Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.



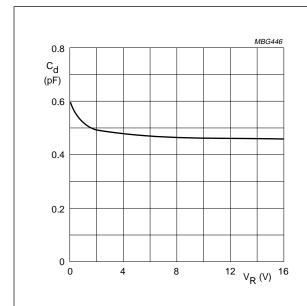
- (1)  $T_j = 150$  °C; typical values.
- (2)  $T_j = 25$  °C; typical values.
- (3)  $T_j = 25$  °C; maximum values.

Fig.3 Forward current as a function of forward voltage.



- (1)  $V_R = 80 V$ ; maximum values.
- (2)  $V_R = 80 \text{ V}$ ; typical values.
- (3)  $V_R = 25 \text{ V}$ ; typical values.

Fig.4 Reverse current as a function of junction temperature.



 $f = 1 \text{ MHz}; T_j = 25 \,^{\circ}\text{C}.$ 

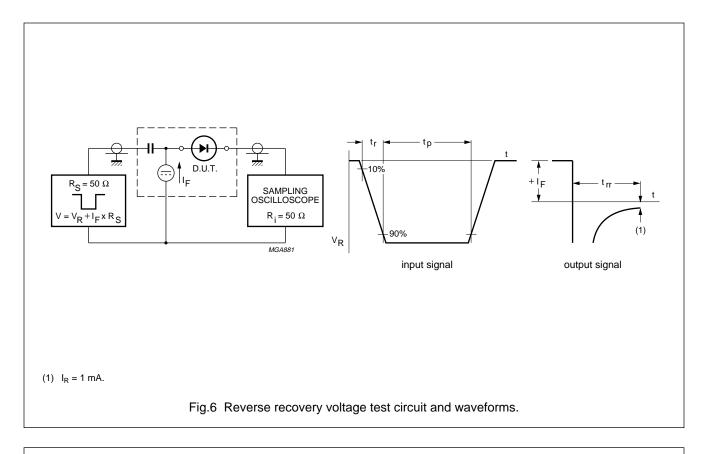
Fig.5 Diode capacitance as a function of reverse voltage; typical values.

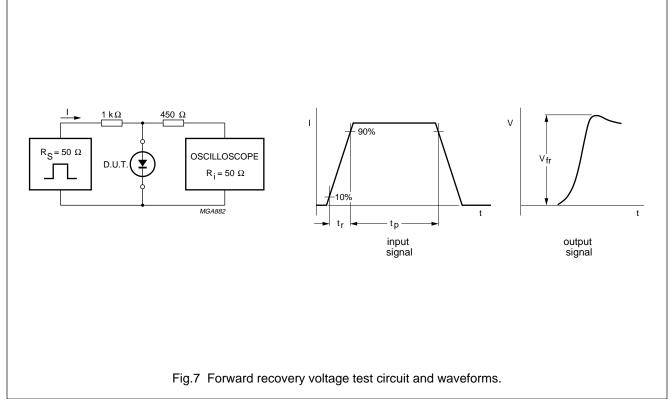
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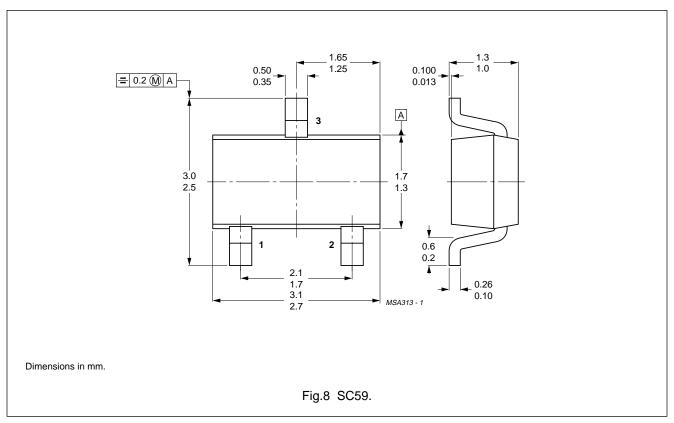
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# High-speed double diode

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#### **PACKAGE OUTLINE**



#### **DEFINITIONS**

Data Sheet Status			
Objective specification	This data sheet contains target or goal specifications for product development.		
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.		
Product specification	This data sheet contains final product specifications.		
Limiting values			
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.			
Application information			
Where application information is given, it is advisory and does not form part of the specification.			

#### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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